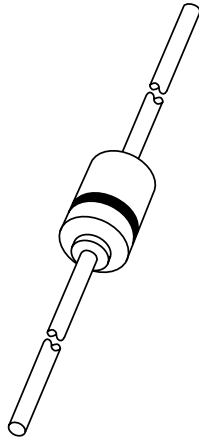


DATA SHEET



BZV85 series Voltage regulator diodes

Product specification
Supersedes data of 1996 Apr 26

1999 May 11

Voltage regulator diodes

BZV85 series

FEATURES

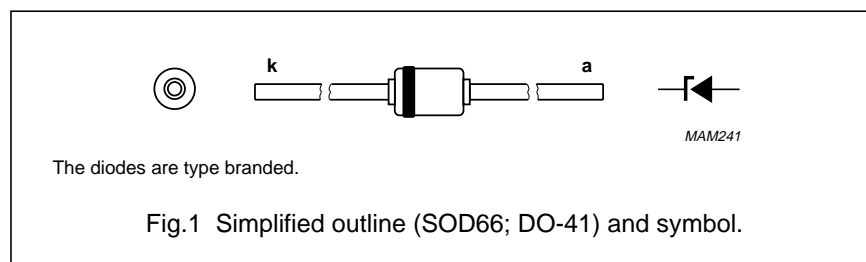
- Total power dissipation: max. 1.3 W
- Tolerance series: approx. $\pm 5\%$
- Working voltage range: nom. 3.6 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 60 W.

APPLICATIONS

- Stabilization purposes.

DESCRIPTION

Medium-power voltage regulator diodes in hermetically sealed leaded glass SOD66 (DO-41) packages. The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 33 types with nominal working voltages from 3.6 to 75 V (BZV85-C3V6 to BZV85-C75).



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|---|---|-------------------------|------|------------------|
| I_F | continuous forward current | | – | 500 | mA |
| I_{ZSM} | non-repetitive peak reverse current | $t_p = 100 \mu\text{s}$; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge; see Fig.3 | see Table "Per type" | | |
| | | $t_p = 10 \text{ ms}$; half sinewave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge | see Table "Per type" | | |
| P_{tot} | total power dissipation | $T_{amb} = 25 \text{ }^\circ\text{C}$; lead length 10 mm; note 1 | – | 1 | W |
| | | note 2 | – | 1.3 | W |
| P_{ZSM} | non-repetitive peak reverse power dissipation | $t_p = 100 \mu\text{s}$; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge | – | 60 | W |
| T_{stg} | storage temperature | | –65 | +200 | $^\circ\text{C}$ |
| T_j | junction temperature | | – | 200 | $^\circ\text{C}$ |

Notes

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.
2. If the leads are kept at $T_{tp} = 55 \text{ }^\circ\text{C}$ at 4 mm from body.

ELECTRICAL CHARACTERISTICS

Total series

$T_j = 25 \text{ }^\circ\text{C}$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MAX. | UNIT |
|--------|-----------------|-----------------------------------|------|------|
| V_F | forward voltage | $I_F = 50 \text{ mA}$; see Fig.4 | 1 | V |

Voltage regulator diodes

BZV85 series

Per type

$T_j = 25\text{ °C}$ unless otherwise specified.

| BZV85- CXXX | WORKING VOLTAGE V_Z (V) at I_{Ztest} | | DIFFERENTIAL RESISTANCE r_{dif} (Ω) at I_{Ztest} | TEMP. COEFF. S_Z (mV/K) at I_{Ztest} see Figs 5 and 6 | | TEST CURRENT I_{Ztest} (mA) | DIODE CAP. C_d (pF) at $f = 1\text{ MHz}$; $V_R = 0\text{ V}$ | REVERSE CURRENT at REVERSE VOLTAGE | | NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} | |
|----------------|--|------|---|--|------|----------------------------------|---|---------------------------------------|-----------|---|---|
| | MIN. | MAX. | MAX. | MIN. | MAX. | | | I_R (μ A) | V_R (V) | at $t_p = 100\ \mu$ s; $T_{amb} = 25\text{ °C}$ | at $t_p = 10\text{ ms}$; $T_{amb} = 25\text{ °C}$ |
| | | | | | | | | | | MAX. (A) | MAX. (mA) |
| 3V6 | 3.4 | 3.8 | 15 | -3.5 | -1.0 | 60 | 450 | 50 | 1.0 | 8.0 | 2000 |
| 3V9 | 3.7 | 4.1 | 15 | -3.5 | -1.0 | 60 | 450 | 10 | 1.0 | 8.0 | 1950 |
| 4V3 | 4.0 | 4.6 | 13 | -2.7 | 0 | 50 | 450 | 5 | 1.0 | 8.0 | 1850 |
| 4V7 | 4.4 | 5.0 | 13 | -2.0 | +0.7 | 45 | 300 | 3 | 1.0 | 8.0 | 1800 |
| 5V1 | 4.8 | 5.4 | 10 | -0.5 | +2.2 | 45 | 300 | 3 | 2.0 | 8.0 | 1750 |
| 5V6 | 5.2 | 6.0 | 7 | 0 | 2.7 | 45 | 300 | 2 | 2.0 | 8.0 | 1700 |
| 6V2 | 5.8 | 6.6 | 4 | 0.6 | 3.6 | 35 | 200 | 2 | 3.0 | 7.0 | 1620 |
| 6V8 | 6.4 | 7.2 | 3.5 | 1.3 | 4.3 | 35 | 200 | 2 | 4.0 | 7.0 | 1550 |
| 7V5 | 7.0 | 7.9 | 3 | 2.5 | 5.5 | 35 | 150 | 1 | 4.5 | 5.0 | 1500 |
| 8V2 | 7.7 | 8.7 | 5 | 3.1 | 6.1 | 25 | 150 | 0.7 | 5.0 | 5.0 | 1400 |
| 9V1 | 8.5 | 9.6 | 5 | 3.8 | 7.2 | 25 | 150 | 0.7 | 6.5 | 4.0 | 1340 |
| 10 | 9.4 | 10.6 | 8 | 4.7 | 8.5 | 25 | 90 | 0.2 | 7.0 | 4.0 | 1200 |
| 11 | 10.4 | 11.6 | 10 | 5.3 | 9.3 | 20 | 85 | 0.2 | 7.7 | 3.0 | 1100 |
| 12 | 11.4 | 12.7 | 10 | 6.3 | 10.8 | 20 | 85 | 0.2 | 8.4 | 3.0 | 1000 |
| 13 | 12.4 | 14.1 | 10 | 7.4 | 12.0 | 20 | 80 | 0.2 | 9.1 | 3.0 | 900 |
| 15 | 13.8 | 15.6 | 15 | 8.9 | 13.6 | 15 | 75 | 0.05 | 10.5 | 2.5 | 760 |
| 16 | 15.3 | 17.1 | 15 | 10.7 | 15.4 | 15 | 75 | 0.05 | 11.0 | 1.75 | 700 |
| 18 | 16.8 | 19.1 | 20 | 11.8 | 17.1 | 15 | 70 | 0.05 | 12.5 | 1.75 | 600 |
| 20 | 18.8 | 21.2 | 24 | 13.6 | 19.1 | 10 | 60 | 0.05 | 14.0 | 1.75 | 540 |
| 22 | 20.8 | 23.3 | 25 | 16.6 | 22.1 | 10 | 60 | 0.05 | 15.5 | 1.5 | 500 |
| 24 | 22.8 | 25.6 | 30 | 18.3 | 24.3 | 10 | 55 | 0.05 | 17 | 1.5 | 450 |
| 27 | 25.1 | 28.9 | 40 | 20.1 | 27.5 | 8 | 50 | 0.05 | 19 | 1.2 | 400 |
| 30 | 28.0 | 32.0 | 45 | 22.4 | 32.0 | 8 | 50 | 0.05 | 21 | 1.2 | 380 |

Voltage regulator diodes

BZV85 series

| BZV85- CXXX | WORKING VOLTAGE V_Z (V) at I_{Ztest} | | DIFFERENTIAL RESISTANCE r_{dif} (Ω) at I_{Ztest} | TEMP. COEFF. S_Z (mV/K) at I_{Ztest} see Figs 5 and 6 | | TEST CURRENT I_{Ztest} (mA) | DIODE CAP. C_d (pF) at $f = 1$ MHz; $V_R = 0$ V | REVERSE CURRENT at REVERSE VOLTAGE | | NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} | |
|----------------|---|------|--|--|------|-------------------------------------|--|---|--------------|---|---|
| | MIN. | MAX. | MAX. | MIN. | MAX. | | | I_R (μ A) | V_R (V) | at $t_p = 100 \mu$ s; $T_{amb} = 25^\circ$ C | at $t_p = 10$ ms; $T_{amb} = 25^\circ$ C |
| | | | | | | | | | | MAX. (A) | MAX. (mA) |
| 33 | 31.0 | 35.0 | 45 | 24.8 | 35.0 | 8 | 45 | 0.05 | 23 | 1.0 | 350 |
| 36 | 34.0 | 38.0 | 50 | 27.2 | 39.9 | 8 | 45 | 0.05 | 25 | 0.9 | 320 |
| 39 | 37.0 | 41.0 | 60 | 29.6 | 43.0 | 6 | 45 | 0.05 | 27 | 0.8 | 296 |
| 43 | 40.0 | 46.0 | 75 | 34.0 | 48.3 | 6 | 40 | 0.05 | 30 | 0.7 | 270 |
| 47 | 44.0 | 50.0 | 100 | 37.4 | 52.5 | 4 | 40 | 0.05 | 33 | 0.6 | 246 |
| 51 | 48.0 | 54.0 | 125 | 40.8 | 56.5 | 4 | 40 | 0.05 | 36 | 0.5 | 226 |
| 56 | 52.0 | 60.0 | 150 | 46.8 | 63.0 | 4 | 40 | 0.05 | 39 | 0.4 | 208 |
| 62 | 58.0 | 66.0 | 175 | 52.2 | 72.5 | 4 | 35 | 0.05 | 43 | 0.4 | 186 |
| 68 | 64.0 | 72.0 | 200 | 60.5 | 81.0 | 4 | 35 | 0.05 | 48 | 0.35 | 171 |
| 75 | 70.0 | 80.0 | 225 | 66.5 | 88.0 | 4 | 35 | 0.05 | 53 | 0.3 | 161 |

Voltage regulator diodes

BZV85 series

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------|---|-----------------------------|-------|------|
| $R_{th\ j-tp}$ | thermal resistance from junction to tie-point | lead length 4 mm; see Fig.2 | 110 | K/W |
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | lead length 10 mm; note 1 | 175 | K/W |

Note

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.

GRAPHICAL DATA

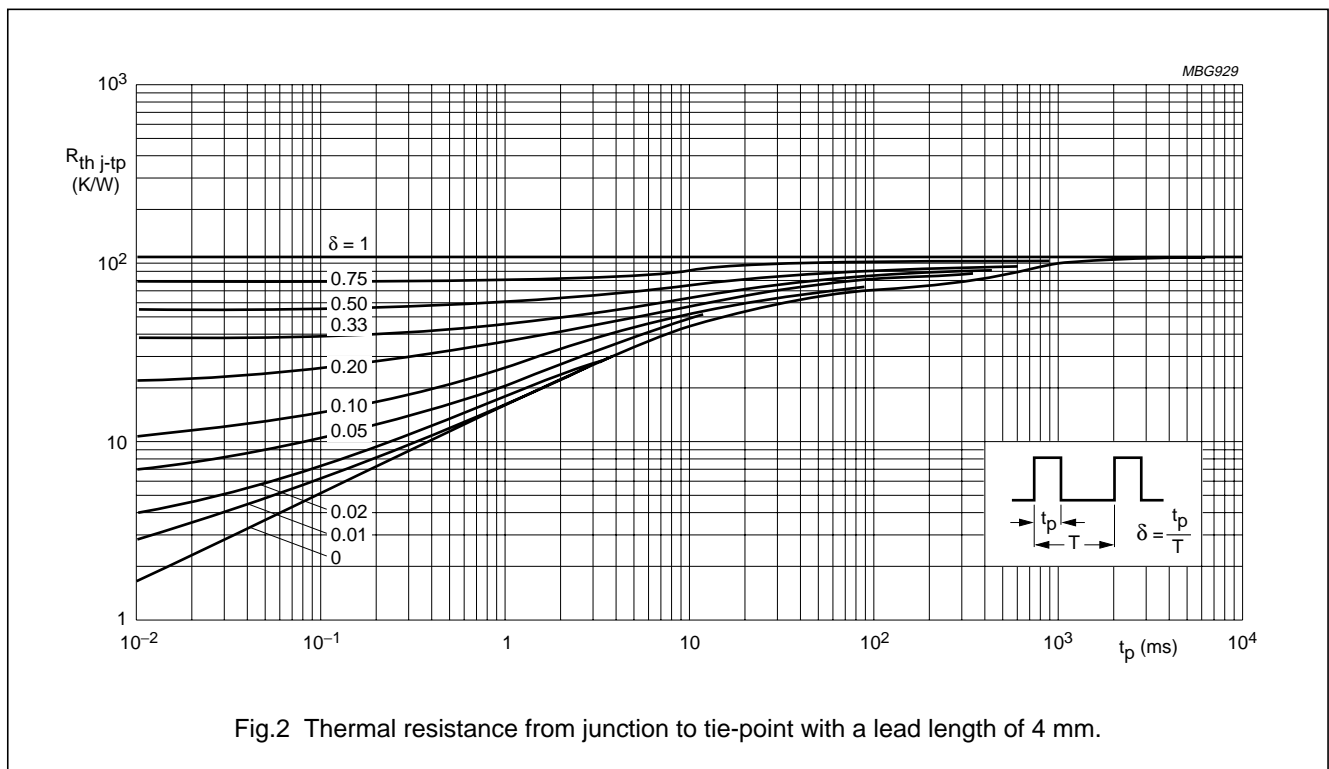
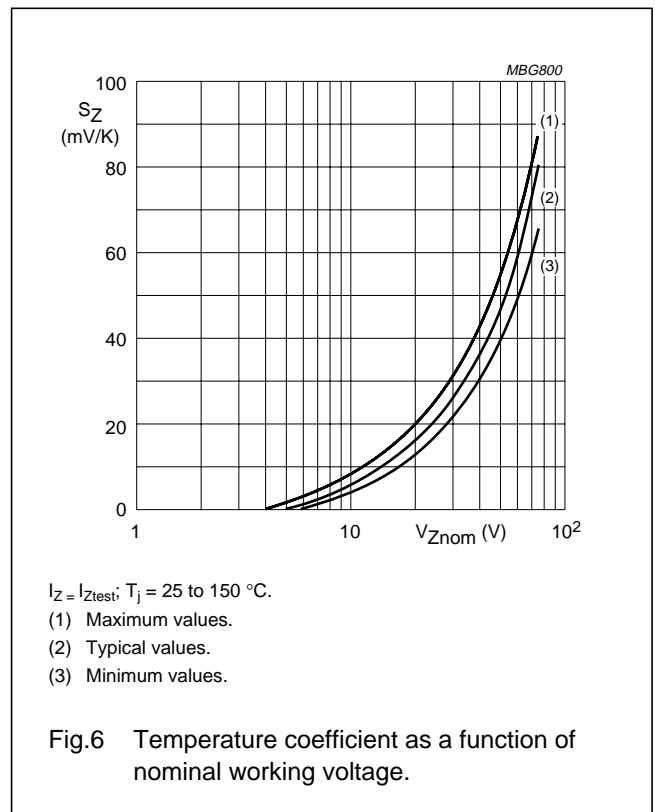
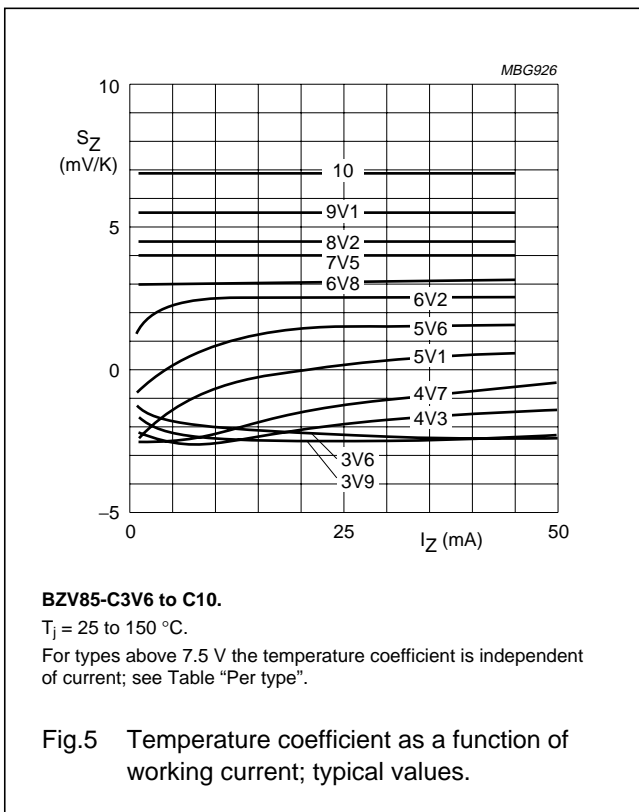
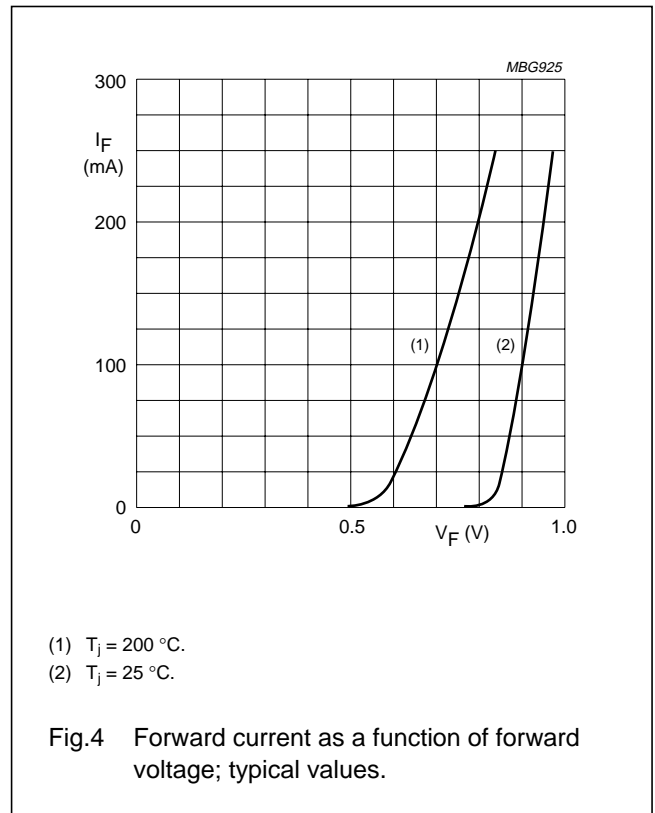
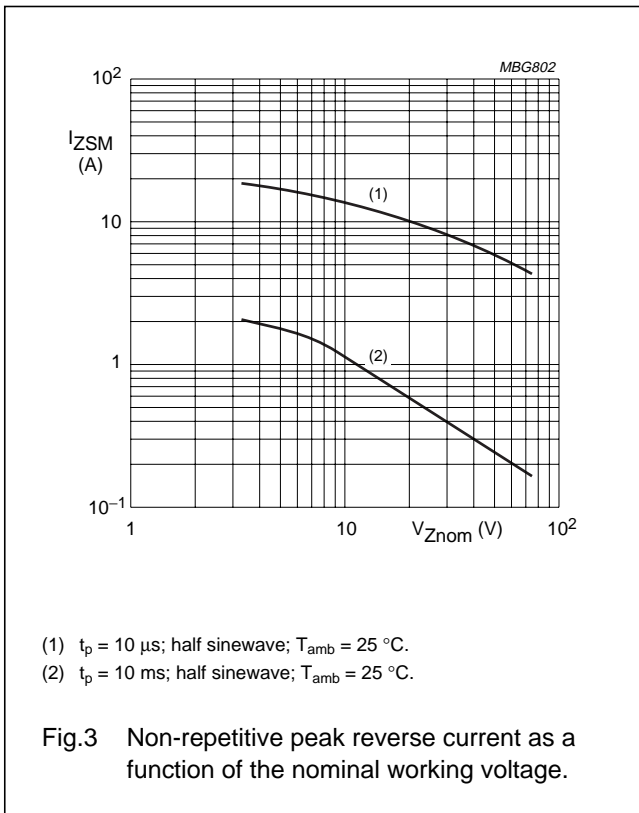


Fig.2 Thermal resistance from junction to tie-point with a lead length of 4 mm.

Voltage regulator diodes

BZV85 series



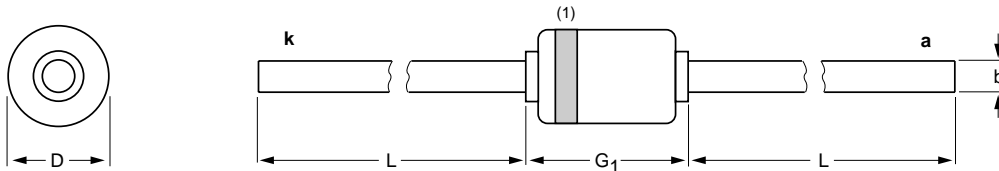
Voltage regulator diodes

BZV85 series

PACKAGE OUTLINE

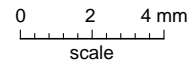
Hermetically sealed glass package; axial leaded; 2 leads

SOD66



DIMENSIONS (mm are the original dimensions)

| UNIT | b max. | D max. | G ₁ max. | L min. |
|------|--------|--------|---------------------|--------|
| mm | 0.81 | 2.6 | 4.8 | 28 |



Note

1. The marking band indicates the cathode.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|------|---------------------|------------|
| | IEC | JEDEC | EIAJ | | |
| SOD66 | | DO-41 | | | 97-06-20 |

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| Data sheet status | |
|---|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
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Printed in The Netherlands

115002/00/02/pp8

Date of release: 1999 May 11

Document order number: 9397 750 05929

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